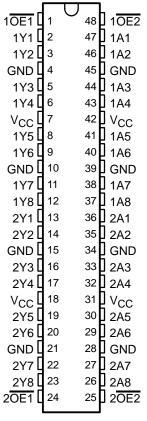
SCAS569D - MARCH 1996 - REVISED JUNE 1997

- Member of the Texas Instruments
 Widebus™ Family
- EPIC[™] (Enhanced-Performance Implanted CMOS) Submicron Process
- Typical V_{OLP} (Output Ground Bounce)
 < 0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 2 V at V_{CC} = 3.3 V, T_A = 25°C
- Supports Mixed-Mode Signal Operation on All Ports (5-V Input/Output Voltage With 3.3-V V_{CC})
- Power Off Disables Inputs/Outputs, Permitting Live Insertion
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Package Options Include Plastic 300-mil Shrink Small-Outline (DL) and Thin-Shrink Small-Outline (DGG) Packages

description

This 16-bit buffer/driver is designed for 2.7-V to 3.6-V V_{CC} operation, and provides a high-performance bus interface for wide data paths.

DGG OR DL PACKAGE (TOP VIEW)



The 3-state control gate is a 2-input AND gate with active-low inputs so that if either output-enable ($\overline{OE1}$ or $\overline{OE2}$) input is high, all corresponding outputs are in the high-impedance state.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The SN74LVCH16540A is characterized for operation from -40°C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

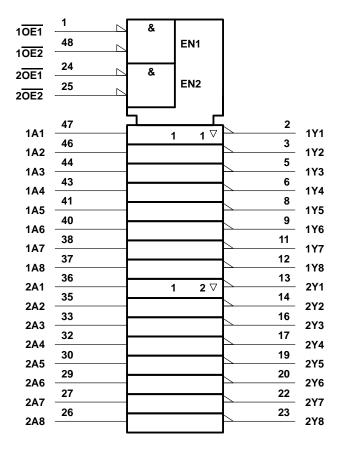
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FUNCTION TABLE (each 8-bit section)

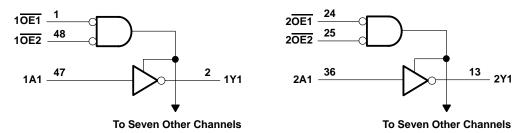
INPUTS			OUTPUT
OE1	OE2	Α	Y
L	L	L	Н
L	L	Н	L
Н	X	Χ	Z
Х	Н	Χ	Z

logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	0.5 V to 6.5 V
Input voltage range, V _I (see Note 1)	0.5 V to 6.5 V
Voltage range applied to any output in the high-impedance or power-off state, VO	
(see Note 1)	–0.5 V to 6.5 V
Voltage range applied to any output in the high or low state, VO	
(see Notes 1 and 2)	$0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I _{IK} (V _I < 0)	
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC})	±50 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC}) (see Note 2)	±50 mA
Continuous current through each V _{CC} or GND	±100 mA
Package thermal impedance, θ _{JA} (see Note 3): DGG package	89°C/W
DL package	94°C/W
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

- 2. The value of V_{CC} is provided in the recommended operating conditions table.
- 3. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 4)

			MIN	MAX	UNIT	
Voc	Complexed	Operating	2	3.6	V	
Vcc	Supply voltage	Data retention only	1.5			
VIH	High-level input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		V	
V_{IL}	Low-level input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8	V	
٧ _I	Input voltage		0	5.5	V	
Va	Output voltage	High or low state	0	VCC	V	
VО		3 state	0	5.5	٧	
lau	V _{CC} = 2.7 V			-12	mA	
ЮН	High-level output current	V _{CC} = 3 V		-24	IIIA	
lOL	V _{CC} = 2.7 V			12	mA	
	Low-level output current	V _{CC} = 3 V		24	IIIA	
Δt/Δν	Input transition rise or fall rate		0	10	ns/V	
TA	Operating free-air temperature		-40	85	°C	

NOTE 4: Unused control inputs must be held high or low to prevent them from floating.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		VCC	MIN	TYP [†]	MAX	UNIT	
	$I_{OH} = -100 \mu A$		2.7 V to 3.6 V	V _{CC} -0.2				
Vou	I _{OH} = -12 mA		2.7 V	2.2			٧	
Voн			3 V	2.4				
	I _{OH} = -24 mA		3 V	2.2				
	I _{OL} = 100 μA		2.7 V to 3.6 V			0.2		
V _{OL}	I _{OL} = 12 mA		2.7 V			0.4	V	
	$I_{OL} = 24 \text{ mA}$		3 V			0.55		
lį	V _I = 0 to 5.5 V		3.6 V			±5	μΑ	
	V _I = 0.8 V		3 V	75				
l _{l(hold)}	V _I = 2 V		3 V	-75			μΑ	
	$V_{\parallel} = 0 \text{ to } 3.6 \text{ V}^{\ddagger}$		3.6 V			±500		
l _{off}	V_I or $V_O = 5.5 V$		0			±10	μΑ	
loz	$V_0 = 0 \text{ to } 5.5 \text{ V}$	V _O = 0 to 5.5 V				±10	μΑ	
la a	$V_I = V_{CC}$ or GND	1- 0	261/			20	_	
Icc	3.6 V ≤ V _I ≤ 5.5 V§	IO = 0	3.6 V		20		μΑ	
ΔlCC	One input at V _{CC} – 0.6 V,	Other inputs at V _{CC} or GND	2.7 V to 3.6 V			500	μΑ	
C _i	$V_I = V_{CC}$ or GND		3.3 V		5		pF	
Co	V _O = V _{CC} or GND		3.3 V		6.5		pF	

switching characteristics over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 2.7 V		UNIT
	(INFOT)		MIN	MAX	MIN	MAX	
^t pd	Α	Υ	1	3.7		4.5	ns
t _{en}	ŌE	Υ	1.5	4.8		5.9	ns
^t dis	ŌE	Υ	1.6	5.9		6.3	ns
t _{sk(o)} ¶				1.7			ns

[¶] Skew between any two outputs of the same package switching in the same direction. This parameter is warranted but not production tested.

operating characteristics, $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$

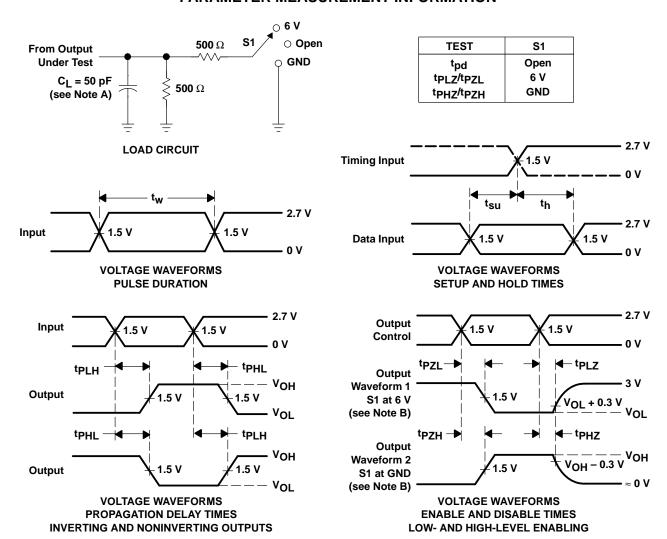
PARAMETER			TEST C	ONDITIONS	TYP	UNIT
C _{pd}	Down dissination conscitones now huffer/driver	Outputs enabled	C _L = 0,	f = 10 MHz	34	pF
	Power dissipation capacitance per buffer/driver	Outputs disabled			2	



[†] All typical values are at V_{CC} = 3.3 V, T_A = 25°C. ‡ This is the bus-hold maximum dynamic current required to switch the input from one state to another.

[§] This applies in the disabled state only.

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \ \Omega$, $t_f \leq 2.5 \ ns$, $t_f \leq 2.5 \ ns$.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpzL and tpzH are the same as ten.
- F. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- G. tpLH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms

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